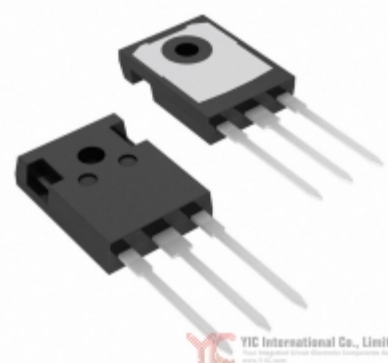


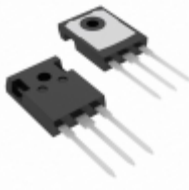


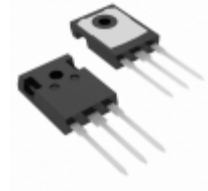
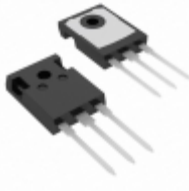
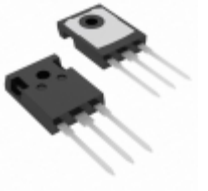
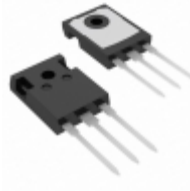
	FGH20N6S2	
	Hersteller-Teilenummer:	FGH20N6S2
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	IGBT 600V 28A 125W TO247
	Datenblätter:	 FGH20N6S2.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 5640 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FGH20N6S2
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 28A 125W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs
Teilstatus	5640 pcs Stock
detaillierte Beschreibung	IGBT 600V 28A 125W Through Hole TO-247-3
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	125W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247-3
Strom - Kollektor (Ic) (max)	28A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 7A
Strom - Collector Pulsed (Icm)	40A
Schaltenergie	25µJ (on), 58µJ (off)
Gate-Ladung	30nC
Td (ein / aus) bei 25 ° C	7.7ns/87ns
Testbedingung	390V, 7A, 25 Ohm, 15V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FGH20N6S2_NL

FGH20N6S2 ist neu im Original, Suche FGH20N6S2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH20N6S2 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH20N6S2: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FGH20N60UFDTU(FGH20N60UFD) Fairchild/ON Semiconductor FGH20N60UFDTU(FGH20N60UFD) FAIRCHILD</p>	 <p>FGH25N120FTDS Fairchild/ON Semiconductor IGBT 1200V 50A 313W TO247</p>	 <p>FGH20N60UFD FAIRCHI FGH20N60UFD FAIRCHI</p>	 <p>FGH20N60SFDTU_F085 Fairchild/ON Semiconductor IGBT 600V 20A 165W TO247</p>
 <p>FGH20N6S2D Fairchild/ON Semiconductor IGBT 600V 28A 125W TO247</p>	 <p>FGH25N120FTDS AMI Semiconductor / ON Semiconductor IGBT 1200V 50A 313W TO247</p>	 <p>FGH20N6S2D AMI Semiconductor / ON Semiconductor IGBT 600V 28A 125W TO247</p>	 <p>FGH20N60UFDTU Fairchild/ON Semiconductor IGBT 600V 40A 165W TO247</p>

heiße Teile

Mehr

 FGH20N60SFD	 FGH20N60SFDTU	 FGH20N60SFDTU	 D FGH20N60UFD	 FGH20N60UFDTU
 FGH20N60UFDTU	 FGH20N6S2	 D FGH20N6S2D	 FGH20N6S2D	 FGH25N120FTDS
 FGH25N120FTDS	 FGH30N120FTD	 FGH30N120FTDTU	 FGH30N120FTDTU	 FGH30N60LSD
 D FGH30N60LSDTU	 FGH30N60LSDTU	 FGH30N6S2	 FGH30N6S2	 FGH30N6S2D
 FGH30N6S2D	 FGH30S130P	 FGH30S130P	 FGH30T65UPDT	 FGH40N60SF
 FGH40N60SFD	 FGH40N60SFDTU	 D FGH40N60SFDTU	 FGH40N60SFTU	 FGH40N60SFTU
 FGH40N60SMD	 D FGH40N60SMD	 FGH40N60SMDF	 FGH40N60SMDF	 FGH40N60UF
 FGH40N60UFD	 FGH40N60UFDTU	 FGH40N60UFDTU	 FGH40N60UFTU	 FGH40N60UFTU
 FGH40N65UFD	 FGH40N65UFDTU	 FGH40N65UFDTU	 D FGH40N6S2	 FGH40N6S2
 FGH40N6S2D	 FGH40N6S2D	 FGH40T100SMD	 FGH40T100SMD	 FGH40T120SMD

Contact us: Info@Y-IC.com

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